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2N6071A/B Series

Preferred Device

Sensitive Gate Triacs

Silicon Bidirectional Thyristors

Designed primarily for full-wave ac control applications, such as light dimmers, motor controls, heating controls and power supplies; or wherever full-wave silicon gate controlled solid-state devices are needed. Triac type thyristors switch from a blocking to a conducting state for either polarity of applied anode voltage with positive or negative gate triggering.

- Sensitive Gate Triggering Uniquely Compatible for Direct Coupling to TTL, HTL, CMOS and Operational Amplifier Integrated Circuit Logic Functions
- Gate Triggering 4 Mode 2N6071A,B, 2N6073A,B, 2N6075A,B
- Blocking Voltages to 600 Volts
- All Diffused and Glass Passivated Junctions for Greater Parameter Uniformity and Stability
- Small, Rugged, Thermopad Construction for Low Thermal Resistance, High Heat Dissipation and Durability
- Device Marking: Device Type, e.g., 2N6071A, Date Code

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
*Peak Repetitive Off-State Voltage(1) (TJ = -40 to 110°C, Sine Wave, 50 to 60 Hz, Gate Open) 2N6071A,B 2N6073A,B 2N6075A,B	Vdrm, Vrrm	200 400 600	Volts
*On-State RMS Current (T _C = 85°C) Full Cycle Sine Wave 50 to 60 Hz	I _{T(RMS)}	4.0	Amps
*Peak Non–repetitive Surge Current (One Full cycle, 60 Hz, T _J = +110°C)	ITSM	30	Amps
Circuit Fusing Considerations (t = 8.3 ms)	l ² t	3.7	A ² s
*Peak Gate Power (Pulse Width ≤ 1.0 μs, T _C = 85°C)	PGM	10	Watts
*Average Gate Power (t = 8.3 ms, T _C = 85°C)	PG(AV)	0.5	Watt
*Peak Gate Voltage (Pulse Width ≤ 1.0 μs, T _C = 85°C)	VGM	5.0	Volts
*Operating Junction Temperature Range	Тj	-40 to +110	°C
*Storage Temperature Range	Tstg	-40 to +150	°C
Mounting Torque (6-32 Screw) ⁽²⁾	.0750	8.0	in. lb.

*Indicates JEDEC Registered Data.

- (1) VDRM and VRRM for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.
- (2) Torque rating applies with use of a compression washer. Mounting torque in excess of 6 in. lb. does not appreciably lower case-to-sink thermal resistance. Main terminal 2 and heatsink contact pad are common.





ON Semiconductor

http://onsemi.com

TRIACS 4 AMPERES RMS 200 thru 600 VOLTS





STYLE 5

PIN ASSIGNMENT		
1 Main Terminal 1		
2	Main Terminal 2	
3	Gate	

ORDERING INFORMATION

Device	Package	Shipping
2N6071A	TO225AA	500/Box
2N6071B	TO225AA	500/Box
2N6073A	TO225AA	500/Box
2N6073B	TO225AA	500/Box
2N6075A	TO225AA	500/Box
2N6075B	TO225AA	500/Box

Preferred devices are recommended choices for future use and best overall value.

THERMAL CHARACTERISTICS

Characteristic		Max	Unit
*Thermal Resistance, Junction to Case	R _{θJC}	3.5	°C/W
Thermal Resistance, Junction to Ambient	R _{θJA}	75	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	Тլ	260	°C

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted; Electricals apply in both directions)

				· · · · · · · · · · · · · · · · · · ·		1
Characteristic		Symbol	Min	Тур	Max	Unit
DFF CHARACTERISTICS						
*Peak Repetitive Blocking Current (V _D = Rated V _{DRM} , V _{RRM} ; Gate Open)			_	_	10 2	μA mA
ON CHARACTERISTICS	-		-		-	
*Peak On-State Voltage(1) (I _{TM} = ±6 A Peak)		V _{TM}	-	-	2	Volts
*Gate Trigger Voltage (Continuous dc) (Main Terminal Voltage = 12 Vdc, R _L = 100 Ohms, T _J = -40°C) All Quadrants		VGT	_	1.4	2.5	Volts
Gate Non–Trigger Voltage (Main Terminal Voltage = 12 Vdc, R _L = 100 Ohms, T _J = 110°C) All Quadrants		V _{GD}	0.2	_	_	Volts
Tholding Current (Main Terminal Voltage = 12 Vdc, Gate Open, Initiating Current = ± 1 Adc) $(T_J = -40^{\circ}C)$ $(T_J = 25^{\circ}C)$		ΙΗ	_	_	30 15	mA
Turn-On Time (I _{TM} = 14 Adc, I _{GT} = 100 mAdc)		tgt	-	1.5	-	μs
				QUADI (Maximur		
	Туре	^I GT @ Тј	I mA	ll mA	III mA	IV mA
Gate Trigger Current (Continuous dc)	2N6071A	+25°C	5	5	5	10
(Main Terminal Voltage = 12 Vdc, R _L = 100 ohms)	2N6073A 2N6075A	-40°C	20	20	20	30
	2N6071B	+25°C	3	3	3	5
	2N6073B					

DYNAMIC CHARACTERISTICS

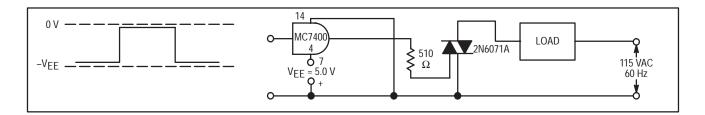
Critical Rate of Rise of Commutation Voltage	dv/dt(c)	—	5	—	V/µs
@ V_{DRM} , $T_J = 85^{\circ}C$, Gate Open, $I_{TM} = 5.7$ A, Exponential Waveform,					
Commutating di/dt = 2.0 A/ms					

*Indicates JEDEC Registered Data.

(1) Pulse Test: Pulse Width \leq 2.0 ms, Duty Cycle \leq 2%.



SAMPLE APPLICATION: TTL-SENSITIVE GATE 4 AMPERE TRIAC TRIGGERS IN MODES II AND III



Trigger devices are recommended for gating on Triacs. They provide:

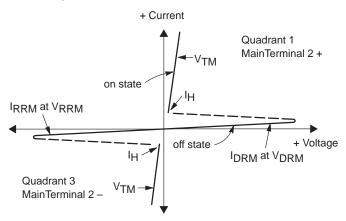
1. Consistent predictable turn-on points.

2. Simplified circuitry.

3. Fast turn-on time for cooler, more efficient and reliable operation.

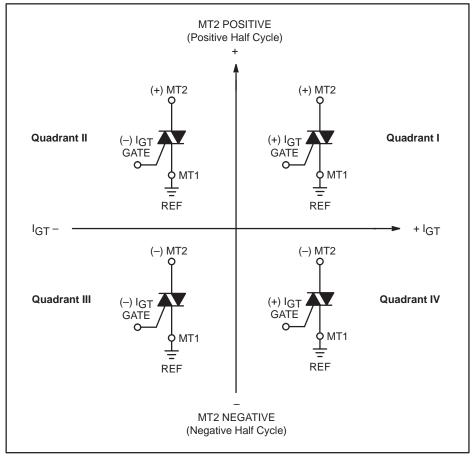
Voltage Current Characteristic of Triacs (Bidirectional Device)

Symbol	Parameter
VDRM	Peak Repetitive Forward Off State Voltage
IDRM	Peak Forward Blocking Current
VRRM	Peak Repetitive Reverse Off State Voltage
IRRM	Peak Reverse Blocking Current
VTM	Maximum On State Voltage
ΙΗ	Holding Current





Quadrant Definitions for a Triac



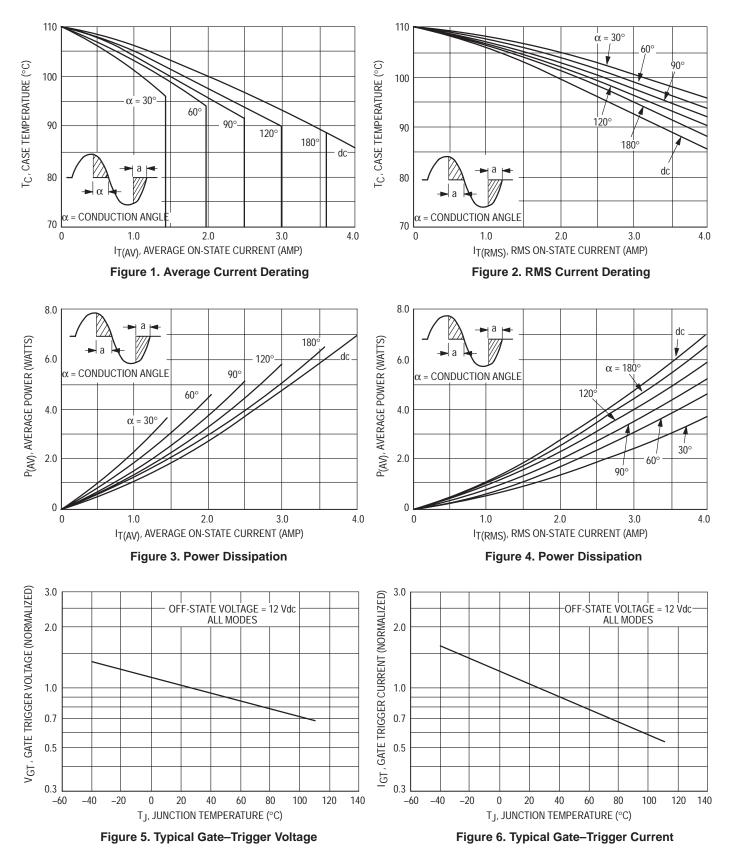
All polarities are referenced to MT1.

With in-phase signals (using standard AC lines) quadrants I and III are used.

IC Logic	Firing Quadrant				
Functions	I	II	ш	IV	
TTL		2N6071A Series	2N6071A Series		
HTL		2N6071A Series	2N6071A Series		
CMOS (NAND)	2N6071B Series			2N6071B Series	
CMOS (Buffer)		2N6071B Series	2N6071B Series		
Operational Amplifier	2N6071A Series			2N6071A Series	
Zero Voltage Switch		2N6071A Series	2N6071A Series		

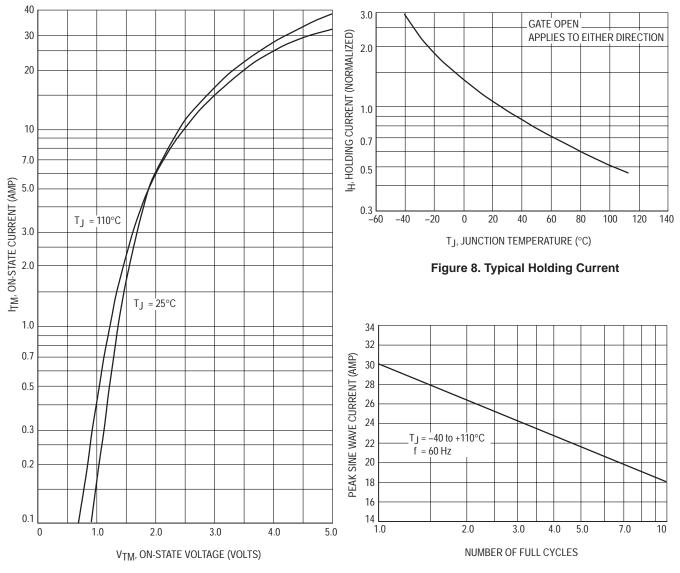
SENSITIVE GATE LOGIC REFERENCE

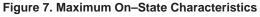




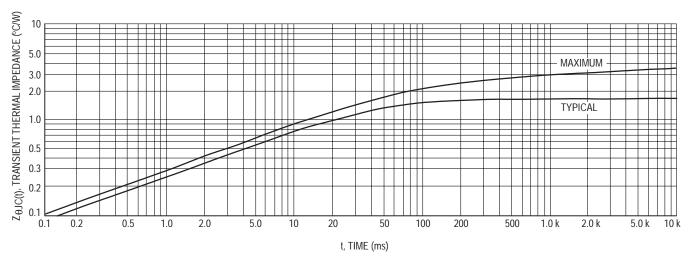
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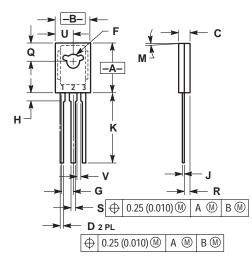






PACKAGE DIMENSIONS

TO-225AA (formerly TO-126) CASE 077-09 ISSUE W



NOT	ES:
1.	DIMENSIONING AND TOLERANCING PER ANSI
	Y14.5M, 1982.
2.	CONTROLLING DIMENSION: INCH.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.425	0.435	10.80	11.04
В	0.295	0.305	7.50	7.74
С	0.095	0.105	2.42	2.66
D	0.020	0.026	0.51	0.66
F	0.115	0.130	2.93	3.30
G	0.094 BSC		2.39 BSC	
Н	0.050	0.095	1.27	2.41
J	0.015	0.025	0.39	0.63
K	0.575	0.655	14.61	16.63
М	5°	TYP	5°	ТҮР
Q	0.148	0.158	3.76	4.01
R	0.045	0.065	1.15	1.65
S	0.025	0.035	0.64	0.88
U	0.145	0.155	3.69	3.93
٧	0.040		1.02	





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